



# **MPS8098**



# **NPN General Purpose Amplifier**

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 300 mA. Sourced from Process 10. See PN100 for characteristics.

## **Absolute Maximum Ratings\***

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CEO}$	Collector-Emitter Voltage	60	V
V <sub>CBO</sub>	Collector-Base Voltage	60	V
V <sub>EBO</sub>	Emitter-Base Voltage	6.0	V
Ic	Collector Current - Continuous	500	mA
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Junction Temperature Range -55 to +150 °C		°C

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

1) These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

# **Thermal Characteristics**

TA = 25°C unless otherwise noted

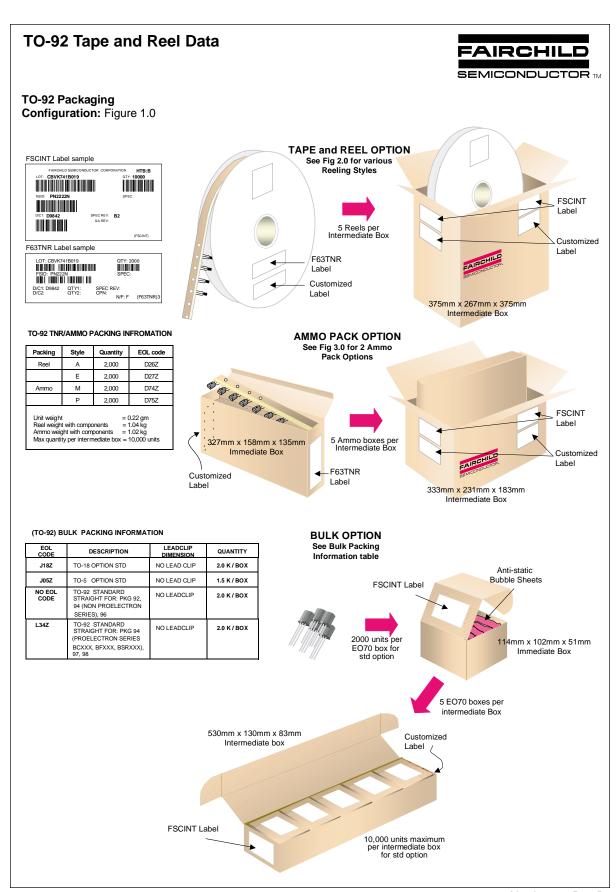
Symbol	Characteristic	Max	Units
		MPS8098	
P <sub>D</sub>	Total Device Dissipation Derate above 25°C	625 5.0	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

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# NPN General Purpose Amplifier (continued)

Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHA	RACTERISTICS				
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage*	$I_C = 10 \text{ mA}, I_B = 0$	60		V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_C = 100 \mu A, I_E = 0$	60		V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = 10  \mu A, I_C = 0$	6.0		V
I <sub>CBO</sub>	Collector Cutoff Current	$V_{CB} = 60 \text{ V}, I_{E} = 0$		0.1	μΑ
I <sub>CEO</sub>	Collector Cutoff Current	$V_{CE} = 60 \text{ V}, I_{B} = 0$		0.1	μΑ
I <sub>EBO</sub>	Emitter Cutoff Current	$V_{EB} = 6.0 \text{ V}, I_{C} = 0$		0.1	μΑ
	RACTERISTICS*				r-
					1
ON CHAF		$V_{CE} = 5.0 \text{ V}, I_{C} = 1.0 \text{ mA}$	100	300	
ON CHAF	RACTERISTICS*	$V_{CE} = 5.0 \text{ V}, I_{C} = 1.0 \text{ mA}$ $V_{CE} = 5.0 \text{ V}, I_{C} = 10 \text{ mA}$	100 100 75	300	
ON CHAF	RACTERISTICS*	$V_{CE} = 5.0 \text{ V}, I_{C} = 1.0 \text{ mA}$	100	300 0.4 0.3	V
	RACTERISTICS*  DC Current Gain	$V_{CE} = 5.0 \text{ V}, I_{C} = 1.0 \text{ mA}$ $V_{CE} = 5.0 \text{ V}, I_{C} = 10 \text{ mA}$ $V_{CE} = 5.0 \text{ V}, I_{C} = 100 \text{ mA}$ $I_{C} = 100 \text{ mA}, I_{B} = 5.0 \text{ mA}$	100	0.4	V
ON CHAF  h <sub>FE</sub> V <sub>CE(sat)</sub> V <sub>BE(on)</sub>	RACTERISTICS*  DC Current Gain  Collector-Emitter Saturation Voltage	$V_{CE} = 5.0 \text{ V}, I_{C} = 1.0 \text{ mA}$ $V_{CE} = 5.0 \text{ V}, I_{C} = 10 \text{ mA}$ $V_{CE} = 5.0 \text{ V}, I_{C} = 100 \text{ mA}$ $I_{C} = 100 \text{ mA}, I_{B} = 5.0 \text{ mA}$ $I_{C} = 100 \text{ mA}, I_{B} = 10 \text{ mA}$	100 75	0.4 0.3	V
ON CHAF  NFE  VCE(sat)  VBE(ON)  SMALL S	RACTERISTICS*  DC Current Gain  Collector-Emitter Saturation Voltage  Base-Emitter On Voltage	$V_{CE} = 5.0 \text{ V}, I_{C} = 1.0 \text{ mA}$ $V_{CE} = 5.0 \text{ V}, I_{C} = 10 \text{ mA}$ $V_{CE} = 5.0 \text{ V}, I_{C} = 100 \text{ mA}$ $I_{C} = 100 \text{ mA}, I_{B} = 5.0 \text{ mA}$ $I_{C} = 100 \text{ mA}, I_{B} = 10 \text{ mA}$	100 75	0.4 0.3	V
ON CHAF  h <sub>FE</sub> V <sub>CE(sat)</sub> V <sub>BE(on)</sub>	RACTERISTICS*  DC Current Gain  Collector-Emitter Saturation Voltage  Base-Emitter On Voltage  IGNAL CHARACTERISTICS	$V_{CE} = 5.0 \text{ V}, I_{C} = 1.0 \text{ mA}$ $V_{CE} = 5.0 \text{ V}, I_{C} = 10 \text{ mA}$ $V_{CE} = 5.0 \text{ V}, I_{C} = 100 \text{ mA}$ $I_{C} = 100 \text{ mA}, I_{B} = 5.0 \text{ mA}$ $I_{C} = 100 \text{ mA}, I_{B} = 10 \text{ mA}$ $V_{CE} = 5.0 \text{ V}, I_{C} = 1.0 \text{ mA}$	100 75	0.4 0.3 0.7	V

<sup>\*</sup>Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%

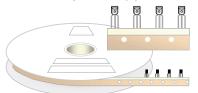


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# TO-92 Tape and Reel Data, continued

# **TO-92 Reeling Style Configuration:** Figure 2.0

### Machine Option "A" (H)



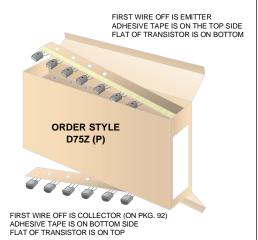
Style "A", D26Z, D70Z (s/h)

# Machine Option "E" (J)

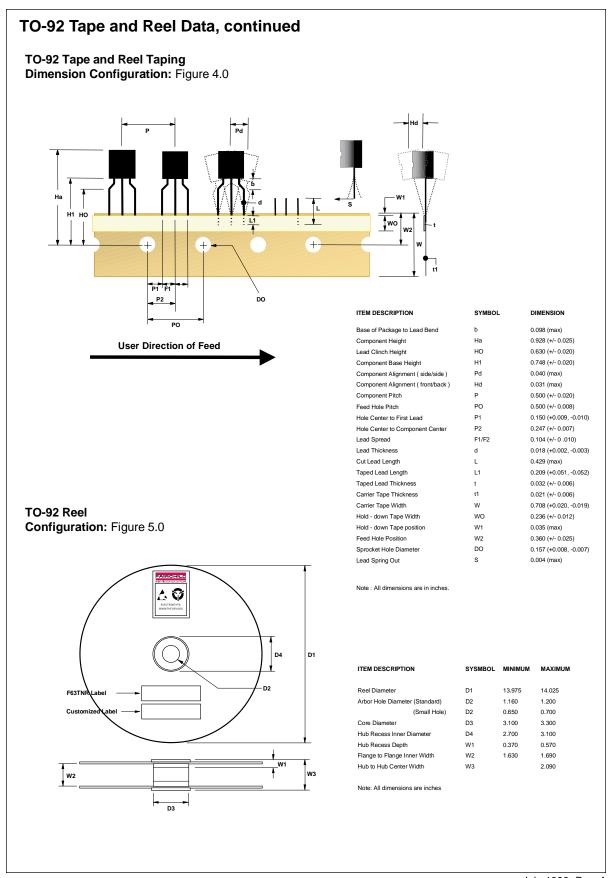
Style "E", D27Z, D71Z (s/h)

# **TO-92 Radial Ammo Packaging Configuration:** Figure 3.0





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# **TO-92 Package Dimensions** FAIRCHILD SEMICONDUCTOR TM TO-92 (FS PKG Code 92, 94, 96) Scale 1:1 on letter size paper Dimensions shown below are in: inches [millimeters] Part Weight per unit (gram): 0.1977 0.185 4.70 0.170 4.32 TO-92 (92,94,96) 94 96 B F В В В D D 2 В S С G Ε Ø0.060 [Ø1.52] G В S С G 0.010 [0.254] DEEP 5.0°TYP.

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0.095 0.084 2.13

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